



SGS-THOMSON
MICROELECTRONICS

查询TBA810供应商

捷多邦，专业PCB打样工厂
，24小时加急出货

TBA810P

7W AUDIO AMPLIFIER

NOT FOR NEW DESIGN

The TBS810P is an improvement of TBA810S.

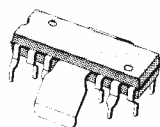
It offers:

- Higher output power ($R_L = 4\Omega$ and 2Ω)
- Low noise
- Polarity inversion protection
- Fortuitous open ground protection
- High supply voltage rejection (40dB min.)

The TBA810P is a monolithic integrated circuit in a 12-lead quad in-line plastic package, intended for use as a low frequency class B amplifier.

The TBA810P provides 7W output power at 16V/4 Ω ; 7W at 14.4/2 Ω .

It gives high output current (up to 3A), high efficiency (75% at 60W output) very low harmonic and crossover distortion. The circuit is provided with a thermal limiting circuit and can withstand a short-circuit on the load for supply voltages up to 15V.



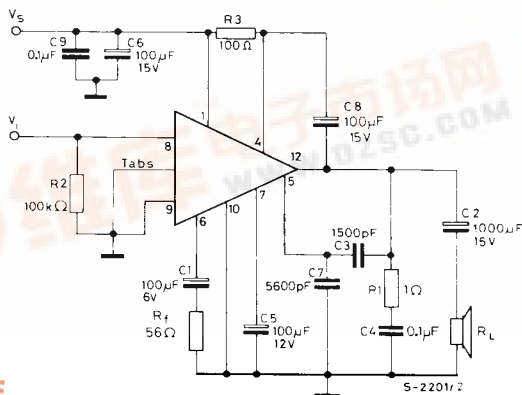
Findip

ORDER CODE: TBA810P

ABSOLUTE MAXIMUM RATINGS

V_s	Supply voltage	20	V
I_o	Output peak current (non repetitive)	4	A
I_o	Output peak current (repetitive)	3	A
P_{tot}	Power dissipation at $T_{amb} \leq 80^\circ C$ $T_{tab} \leq 90^\circ C$	1	W
		5	W
T_{stg}, T_j	Storage and junction temperature	-40 to 150	$^\circ C$

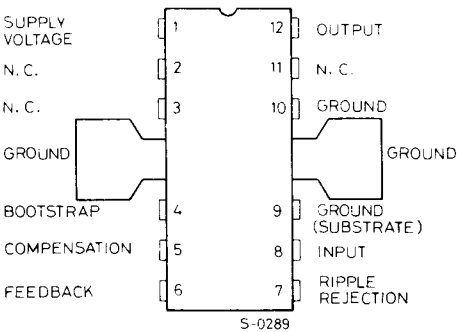
TEST AND APPLICATION CIRCUIT



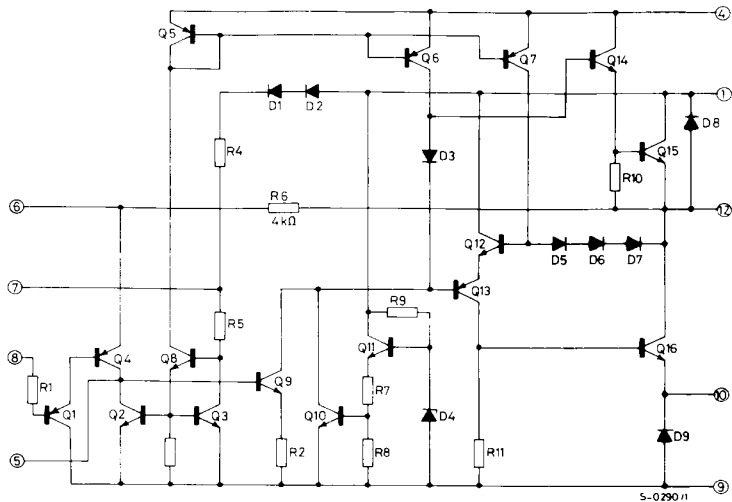
TBA810P

CONNECTION DIAGRAM

(Top view)



SCHEMATIC DIAGRAM



THERMAL DATA

$R_{thj-tab}$	Thermal resistance junction-tab	max	12	$^{\circ}C/W$
$R_{thj-amb}$	Thermal resistance junction-ambient	max	70*	$^{\circ}C/W$

* Obtained with tabs soldered to printed circuit with minimized copper area

ELECTRICAL CHARACTERISTICS (Refer to the test circuit; $V_s = 14.4V$, $T_{amb} = 25^\circ C$ unless otherwise specified)

Parameter		Test Conditions	Min.	Typ.	Max.	Unit	
V _s	Supply voltage (pin 1)		4		20	V	
V _o	Quiescent output voltage (pin 2)		6.4	7.2	8	V	
I _d	Quiescent drain current			12	20	mA	
I _b	Input bias current			0.4		μA	
P _o	Output power	d = 10% R _L = 4Ω R _L = 2Ω	f = 1KHz 5.5 5.5	6 7		W W	
V _{i (rms)}	Input saturation voltage		220			mV	
R _i	Input resistance (pin 8)			5		MΩ	
B	Frequency response (-3dB)	R _L = 4Ω/2Ω C ₃ = 820pF C ₃ = 150pF	40 to 20,000 40 to 10,000			Hz Hz	
d	Distortion	P _o = 50mW to 2.5W R _L = 4Ω/2Ω	f = 1KHz	0.3		%	
G _v	Voltage gain (open loop)	R _L = 4Ω	f = 1KHz	80		dB	
G _v	Voltage gain (closed loop)	R _L = 4Ω/2Ω	f = 1KHz	34	37	40	dB
e _N	Input noise voltage	V _s = 16V B (-3dB) = 40 to 15,000Hz		2		μV	
i _N	Input noise current			80		pA	
η	Efficiency	P _o = 6W f = 1KHz	R _L = 4Ω	75		%	
SVR	Supply voltage rejection	R _L = 4Ω f _{ripple} = 10Hz	V _{ripple} = 1V _{rms}	40	48		dB

Fig. 1 - Output power vs. supply voltage

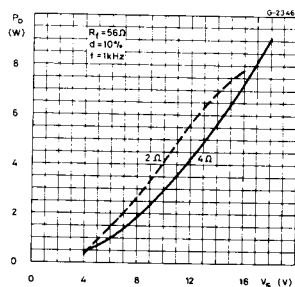


Fig. 2 - Maximum power dissipation vs. supply voltage (sine wave operation)

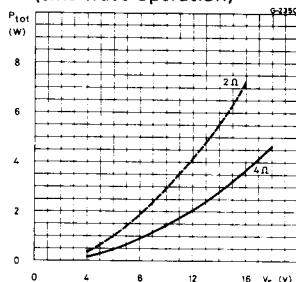


Fig. 3 - Value of C3 vs. feedback resistance for various values of B

